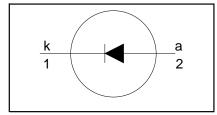
Rectifier diodes fast, soft-recovery

BY329 series

FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristicHigh thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 800 \text{ V/ } 1000 \text{ V/ } 1200 \text{ V}$$

$$I_{F(AV)} = 8 \text{ A}$$

$$I_{FSM} \le 75 \text{ A}$$

$$t_{rr} \le 135 \text{ ns}$$

GENERAL DESCRIPTION

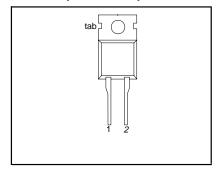
Glass-passivated double diffused rectifier diodes featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The devices are intended for use in TV receivers, monitors and switched mode power supplies.

The BY329 series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	cathode		

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS			MAX.		UNIT
V_{RSM}	Peak non-repetitive reverse voltage	BY329	-	-800 800	-1000 1000	-1200 1200	V
$V_{RRM} \ V_{RWM}$	Peak repetitive reverse voltage Crest working reverse voltage		- -	800 600	1000 800	1200 1000	V V
I _{F(AV)}	Average forward current ¹	square wave; $\delta = 0.5$; $T_{mb} \le 122 ^{\circ}\text{C}$	-		8		А
		sinusoidal; a = 1.57; $T_{mb} \le 125 \degree C$	-		7		Α
I _{F(RMS)}	RMS forward current		-		11		Ą
I _{FRM}	Repetitive peak forward current	t = 25 μs; δ = 0.5; T _{mb} ≤ 122 °C	-		16		Α
I _{FSM}	Non-repetitive peak forward	t = 10 ms	-		75		Α
	current.	t = 8.3 ms sinusoidal; T _i = 150 °C prior to surge; with reapplied	-		82		А
121	120 6 - 10 6 - 10 - 10	V _{RWM(max)}			00		A 2 -
I ² t	l ² t for fusing	t = 10 ms	-		28		A ² s
$egin{bmatrix} {\sf T}_{\sf stg} \ {\sf T}_{\sf j} \ \end{bmatrix}$	Storage temperature Operating junction temperature		-40 -		150 150		ů, Č

¹ Neglecting switching and reverse current losses.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to		-	-	2.0	K/W
R _{th j-a}	mounting base Thermal resistance junction to ambient	in free air.	-	60	-	K/W

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_F = 20 \text{ A}$	-	1.5	1.85	V
I _R	Reverse current	$V_R = V_{RWM}$; $T_j = 125 ^{\circ}\text{C}$		0.1	1.0	mA

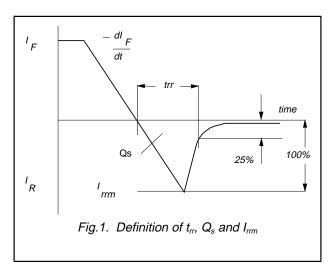
DYNAMIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t_{rr} Q_s dl_R/dt	Reverse recovery charge	$\begin{array}{l} I_F = 1 \text{ A; V}_R \geq 30 \text{ V; } \text{-dI}_F / \text{dt} = 50 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; V}_R \geq 30 \text{ V; } \text{-dI}_F / \text{dt} = 20 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } \text{-dI}_F / \text{dt} = 20 \text{ A/}\mu\text{s} \end{array}$		100 0.5 50	135 0.7 60	ns μC A/μs

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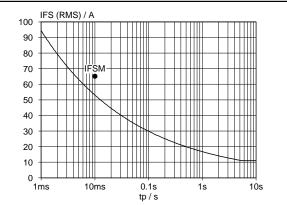


Fig.4. Maximum non-repetitive rms forward current. $I_F = f(t_p)$; sinusoidal current waveform; $T_j = 150^{\circ}\text{C}$ prior to surge with reapplied V_{RWM} .

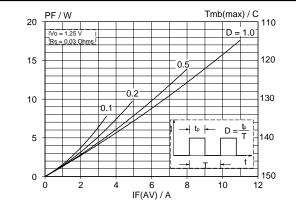


Fig.2. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; square wave current waveform; parameter D = duty cycle = t_p/T .

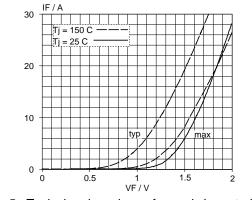


Fig.5. Typical and maximum forward characteristic; $I_F = f(V_F)$; parameter T_j

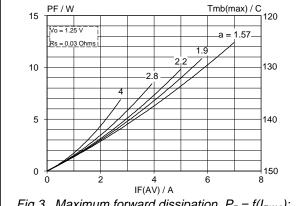
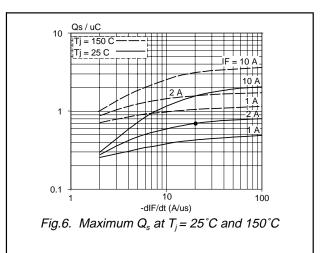


Fig.3. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; sinusoidal current waveform; parameter a = form factor $= I_{F(RMS)}/I_{F(AV)}$.



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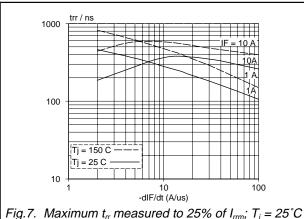


Fig.7. Maximum t_{rr} measured to 25% of I_{rrm} ; $T_j = 25^{\circ}C$ and 150°C

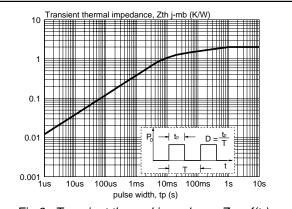


Fig.9. Transient thermal impedance $Z_{th} = f(t_p)$

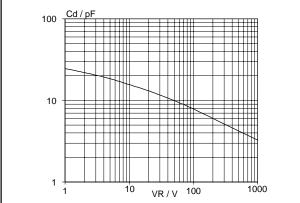
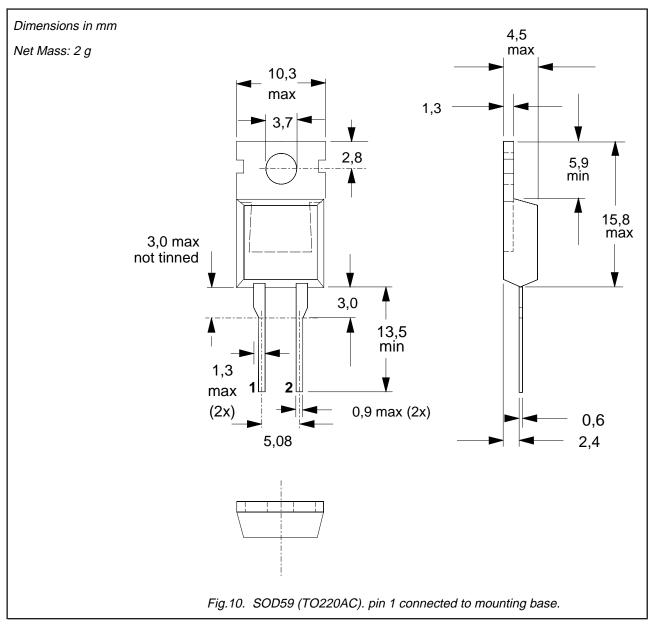


Fig.8. Typical junction capacitance C_d at f = 1 MHz, $T_j = 25^{\circ}C$

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MECHANICAL DATA



- Refer to mounting instructions for TO220 envelopes.
 Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification This data sheet contains final product specifications.				
Limiting values				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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